

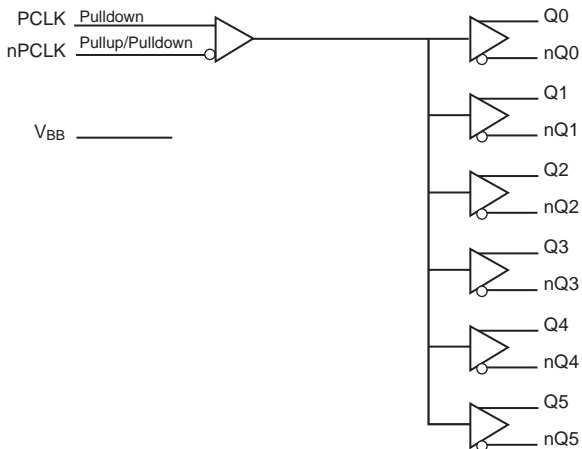
General Description

The ICS853S006I is a low skew, high performance 1-to-6 Differential-to-2.5V/3.3V LVPECL/ECL Fanout Buffer. The ICS853S006I is characterized to operate from either a 2.5V or a 3.3V power supply. Guaranteed output and part-to-part skew characteristics make the ICS853S006I ideal for those clock distribution applications demanding well defined performance and repeatability.

Features

- Six differential 2.5V, 3.3V LVPECL/ECL outputs
- One differential PCLK, nPCLK input pair
- PCLK, nPCLK pair can accept the following differential input levels: LVPECL, LVDS, CML
- Maximum output frequency: 2GHz
- Output skew: 50ps (max)
- Part-to-part skew: 230ps (max)
- Propagation delay: 550ps (max)
- LVPECL mode operating voltage supply range: $V_{CC} = 2.375V$ to $3.465V$, $V_{EE} = 0V$
- ECL mode operating voltage supply range: $V_{CC} = 0V$, $V_{EE} = -2.375V$ to $-3.465V$
- $-40^{\circ}C$ to $85^{\circ}C$ ambient operating temperature
- Available lead-free (RoHS 6) package

Block Diagram



Pin Assignment

V_{CC}	1	20	V_{CC}
nQ0	2	19	Q5
Q0	3	18	nQ5
nQ1	4	17	Q4
Q1	5	16	nQ4
nQ2	6	15	Q3
Q2	7	14	nQ3
V_{CC}	8	13	V_{CC}
PCLK	9	12	V_{EE}
nPCLK	10	11	V_{BB}

ICS853S006I

20-Lead TSSOP

6.5mm x 4.4mm x 0.92mm package body

G Package

Top View

Table 1. Pin Descriptions

Number	Name	Type		Description
1, 8, 13, 20	V _{CC}	Power		Positive supply pin.
2, 3	nQ0, Q0	Output		Differential output pair. LVPECL interface levels.
4, 5	nQ1, Q1	Output		Differential output pair. LVPECL interface levels.
6, 7	nQ2, Q2	Output		Differential output pair. LVPECL interface levels.
9	PCLK	Input	Pulldown	Non-inverting differential LVPECL clock input.
10	nPCLK	Input	Pullup/ Pulldown	Inverting differential LVPECL clock input. V _{CC} /2 default when left floating.
11	V _{BB}	Output		Bias voltage.
12	V _{EE}	Power		Negative supply pin.
14, 15	nQ3, Q3	Output		Differential output pair. LVPECL interface levels.
16, 17	nQ4, Q4	Output		Differential output pair. LVPECL interface levels.
18, 19	nQ5, Q5	Output		Differential output pair. LVPECL interface levels.

NOTE: *Pullup and Pulldown* refer to internal input resistors. See Table 2, *Pin Characteristics*, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
R _{PULLDOWN}	Input Pulldown Resistor			75		kΩ
R _{VCC/2}	Pullup/Pulldown Resistors			50		kΩ

Function Tables

Table 3. Clock Input Function Table

Inputs		Outputs		Input to Output Mode	Polarity
PCLK	nPCLK	Q0:Q5	nQ0:nQ5		
0	1	LOW	HIGH	Differential to Differential	Non-Inverting
1	0	HIGH	LOW	Differential to Differential	Non-Inverting
0	Biased; NOTE 1	LOW	HIGH	Single-Ended to Differential	Non-Inverting
1	Biased; NOTE 1	HIGH	LOW	Single-Ended to Differential	Non-Inverting
Biased; NOTE 1	0	HIGH	LOW	Single-Ended to Differential	Inverting
Biased; NOTE 1	1	LOW	HIGH	Single-Ended to Differential	Inverting

Note 1: Please refer to the Applications Information, "Wiring the Differential Input to Accept Single Ended Levels".

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V_{CC}	4.6V (LVPECL mode, $V_{EE} = 0V$)
Negative Supply Voltage, V_{EE}	-4.6V (ECL mode, $V_{CC} = 0V$)
Inputs, V_I (LVPECL mode)	-0.5V to $V_{CC} + 0.5V$
Inputs, V_I (ECL mode)	0.5V to $V_{EE} - 0.5V$
Outputs, I_O Continuous Current Surge Current	50mA 100mA
V_{BB} Sink//Source, I_{BB}	$\pm 0.5mA$
Operating Temperature Range, T_A	-40°C to +85°C
Package Thermal Impedance, θ_{JA}	92.1°C/W (0 mps)
Storage Temperature, T_{STG}	-65°C to 150°C

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, $V_{CC} = 2.375V$ to $3.465V$; $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{CC}	Positive Supply Voltage		2.375	3.3	3.465	V
I_{EE}	Power Supply Current				60	mA

Table 4B. LVPECL DC Characteristics, $V_{CC} = 3.3V$; $V_{EE} = 0V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

Symbol	Parameter	$-40^{\circ}C$			$25^{\circ}C$			$85^{\circ}C$			Units
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
V_{OH}	Output High Voltage; NOTE 1	2.18	2.37	2.41	2.21	2.35	2.42	2.24	2.34	2.41	V
V_{OL}	Output Low Voltage; NOTE 1	1.405	1.56	1.68	1.425	1.55	1.65	1.44	1.55	1.65	V
V_{SWING}	Peak-to-Peak Output Voltage Swing	625	800	870	690	800	870	730	800	852	mV
V_{IH}	Input High Voltage (Single-ended)	2.075		2.36	2.075		2.36	2.075		2.36	V
V_{IL}	Input Low Voltage (Single-ended)	1.43		1.765	1.43		1.765	1.43		1.765	V
V_{BB}	Output Voltage Reference; NOTE 2	1.86		1.98	1.86		1.98	1.86		1.98	V
V_{PP}	Peak-to-Peak Input Voltage	150	800	1200	150	800	1200	150	800	1200	mV
V_{CMR}	Input High Voltage Common Mode Range; NOTE 3, 4	1.2		V_{CC}	1.2		V_{CC}	1.2		V_{CC}	V
I_{IH}	Input High Current	PCLK, nPCLK		150			150			150	μA
I_{IL}	Input Low Current	PCLK		-10			-10			-10	μA
		nPCLK		-150			-150			-150	μA

NOTE: Input and output parameters vary 1:1 with V_{CC} .

NOTE 1: Outputs terminated with 50Ω to $V_{CCO} - 2V$.

NOTE 2: Single-ended input operation is limited. $V_{CC} \geq 3V$ in LVPECL mode.

NOTE 3: Common mode voltage is defined as V_{IH} .

NOTE 4: For single-ended applications, the maximum input voltage for PCLK, nPCLK is $V_{CC} + 0.3V$

Table 4C. LVPECL DC Characteristics, $V_{CC} = 2.5V$; $V_{EE} = 0V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

Symbol	Parameter	$-40^{\circ}C$			$25^{\circ}C$			$85^{\circ}C$			Units
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
V_{OH}	Output High Voltage; NOTE 1	1.38	1.57	1.61	1.41	1.55	1.62	1.44	1.54	1.61	V
V_{OL}	Output Low Voltage; NOTE 1	0.605	0.76	0.88	0.625	0.75	0.85	0.64	0.75	0.85	V
V_{SWING}	Peak-to-Peak Output Voltage Swing	625	800	870	690	800	870	730	800	852	mV
V_{IH}	Input High Voltage (Single-ended)	1.275		1.56	1.275		1.56	1.275		1.56	V
V_{IL}	Input Low Voltage (Single-ended)	0.63		0.965	0.63		0.965	0.63		0.965	V
V_{PP}	Peak-to-Peak Input Voltage	150	800	1200	150	800	1200	150	800	1200	mV
V_{CMR}	Input High Voltage Common Mode Range; NOTE 2, 3	1.2		V_{CC}	1.2		V_{CC}	1.2		V_{CC}	V
I_{IH}	Input High Current	PCLK, nPCLK		150			150			150	μA
I_{IL}	Input Low Current	PCLK		-10			-10			-10	μA
		nPCLK		-150			-150			-150	μA

NOTE: Input and output parameters vary 1:1 with V_{CC} .

NOTE 1: Outputs terminated with 50Ω to $V_{CCO} - 2V$.

NOTE 2: Common mode voltage is defined as V_{IH} .

NOTE 3: For single-ended applications, the maximum input voltage for PCLK, nPCLK is $V_{CC} + 0.3V$.

Table 4D. ECL DC Characteristics, $V_{CC} = 0V$; $V_{EE} = -3.465V$ to $-2.375V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

Symbol	Parameter	$-40^{\circ}C$			$25^{\circ}C$			$85^{\circ}C$			Units
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
V_{OH}	Output High Voltage; NOTE 1	-1.12	-0.93	-0.89	-1.09	-0.95	-0.88	-1.06	-0.96	-0.89	V
V_{OL}	Output Low Voltage; NOTE 1	-1.895	-1.74	-1.62	-1.875	-1.75	-1.65	-1.86	-1.75	-1.65	V
V_{SWING}	Peak-to-Peak Output Voltage Swing	625	800	870	690	800	870	730	800	852	mV
V_{IH}	Input High Voltage (Single-ended)	-1.225		-0.94	-1.225		-0.94	-1.225		-0.94	V
V_{IL}	Input Low Voltage (Single-ended)	-1.87		-1.535	-1.87		-1.535	-1.87		-1.535	V
V_{BB}	Output Voltage Reference; NOTE 2	-1.44		-1.32	-1.44		-1.32	-1.44		-1.32	V
V_{PP}	Peak-to-Peak Input Voltage	150	800	1200	150	800	1200	150	800	1200	mV
V_{CMR}	Input High Voltage Common Mode Range; NOTE 3, 4	$V_{EE}+1.2$		0	$V_{EE}+1.2$		0	$V_{EE}+1.2$		0	V
I_{IH}	Input High Current	PCLK, nPCLK		150			150			150	μA
		PCLK	-10			-10			-10		μA
I_{IL}	Input Low Current	nPCLK	-150			-150			-150		μA

NOTE 1: Outputs terminated with 50Ω to $V_{CCO} - 2V$.

NOTE 2: Single-ended input operation is limited. $V_{EE} \leq -3V$ in LVPECL mode.

NOTE 3: Common mode voltage is defined as V_{IH} .

NOTE 4: For single-ended applications, the maximum input voltage for PCLK, nPCLK is $V_{CC} + 0.3V$

AC Electrical Characteristics

Table 5. AC Characteristics, $V_{CC} = 0$; $V_{EE} = -2.375V$ to $-3.465V$ or , $V_{CC} = 2.375V$ to $3.465V$; $V_{EE} = 0V$,
 $T_A = -40^{\circ}C$ to $85^{\circ}C$

Symbol	Parameter	-40°C			25°C			85°C			Units	
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max		
f_{OUT}	Output Frequency			2			2			2	GHz	
t_{PD}	Propagation Delay; NOTE 1	230	375	530	260	400	535	300	420	550	ps	
$t_{sk(o)}$	Output Skew; NOTE 2, 4		21	50		22	50		23	50	ps	
$t_{sk(pp)}$	Part-to-Part Skew; NOTE 3, 4			230			230			230	ps	
f_{jit}	Buffer Additive Phase Jitter, RMS; 156.25MHz, Integration Range: 1kHz – 40MHz, refer to Additive Phase Jitter Section		0.08			0.09			0.10		ps	
t_R / t_F	Output Rise/Fall Time	20% to 80%	55	136	240	55	140	240	55	150	240	ps
		10% to 90%	65	210	400	65	210	400	65	230	400	ps

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE: All parameters are measured at $f \leq 1GHz$, unless otherwise noted.

NOTE 1: Measured from the differential input crossing point to the differential output crossing point.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at the output differential cross points.

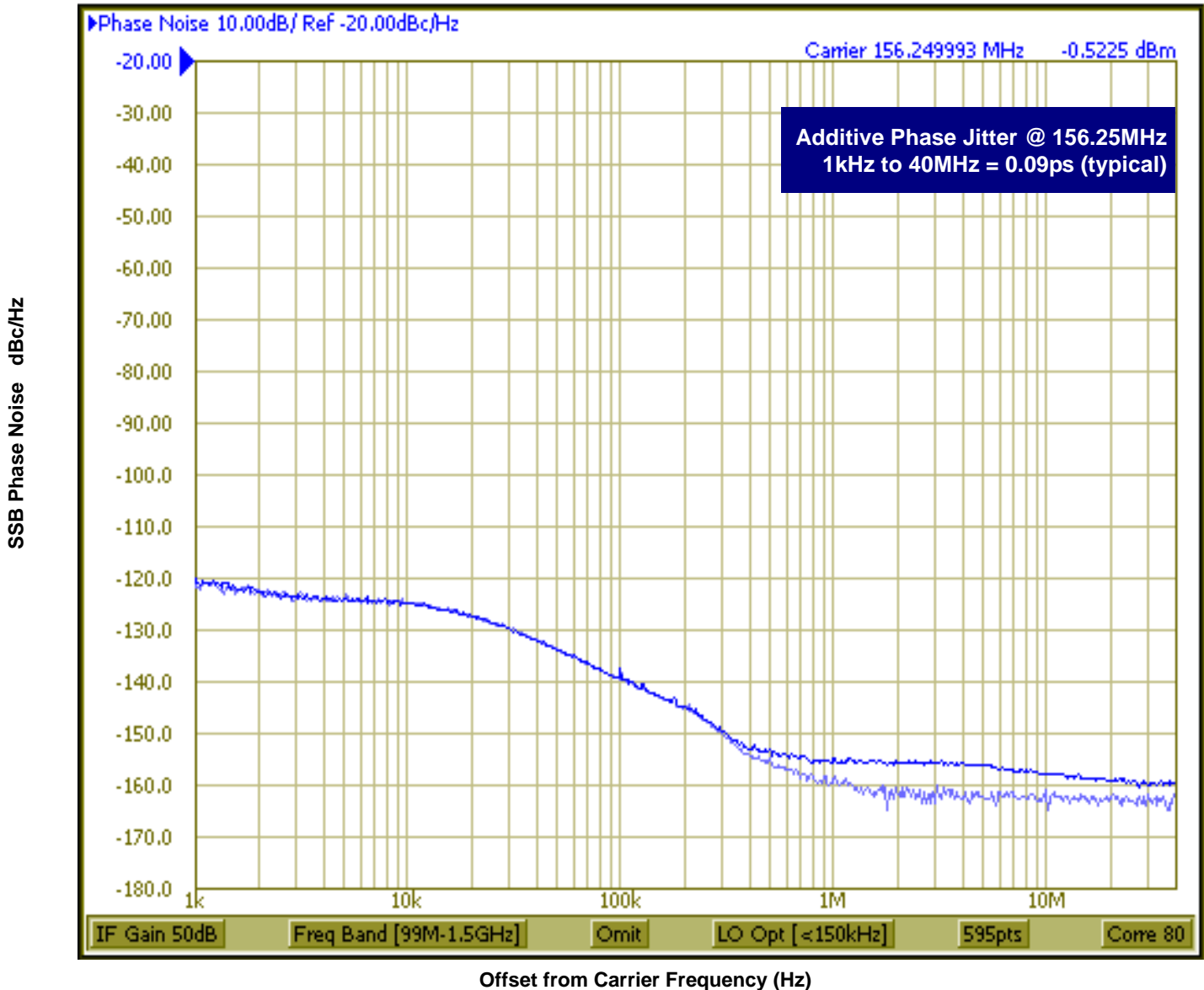
NOTE 3: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

Additive Phase Jitter

The spectral purity in a band at a specific offset from the fundamental compared to the power of the fundamental is called the **dBc Phase Noise**. This value is normally expressed using a Phase noise plot and is most often the specified plot in many applications. Phase noise is defined as the ratio of the noise power present in a 1Hz band at a specified offset from the fundamental frequency to the power value of the fundamental. This ratio is expressed in decibels (dBm)

or a ratio of the power in the 1Hz band to the power in the fundamental. When the required offset is specified, the phase noise is called a **dBc** value, which simply means dBm at a specified offset from the fundamental. By investigating jitter in the frequency domain, we get a better understanding of its effects on the desired application over the entire time record of the signal. It is mathematically possible to calculate an expected bit error rate given a phase noise plot.

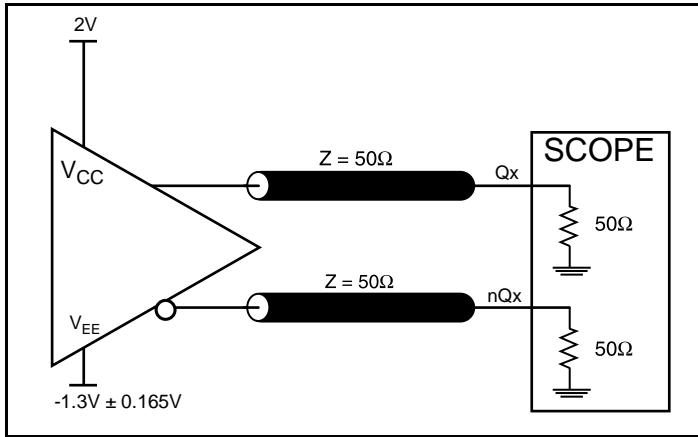


As with most timing specifications, phase noise measurements has issues relating to the limitations of the equipment. Often the noise floor of the equipment is higher than the noise floor of the device. This is illustrated above.

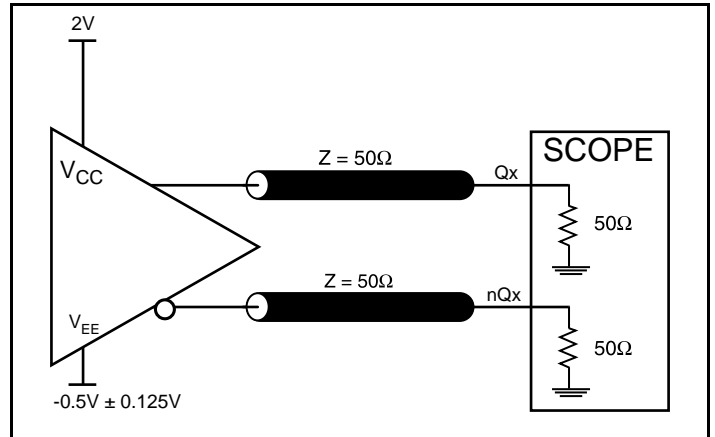
The device meets the noise floor of what is shown, but can actually be lower. The phase noise is dependent on the input source and measurement equipment.

Measured using a Rhode & Schwarz SMA 100 as the input source.

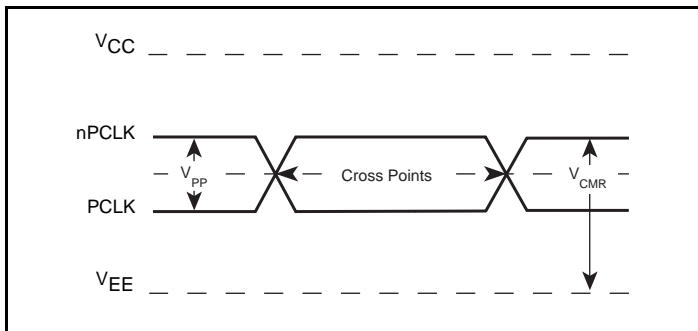
Parameter Measurement Information



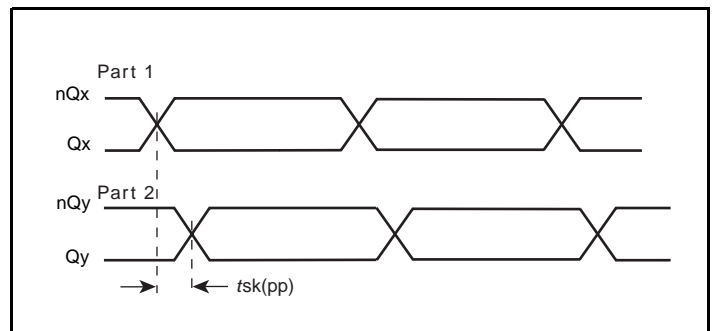
3.3V LVPECL Output Load AC Test Circuit



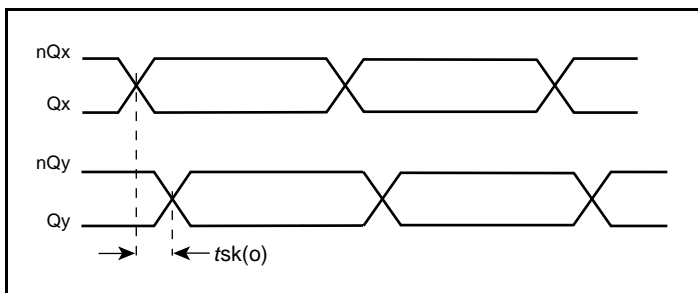
2.5V LVPECL Output Load AC Test Circuit



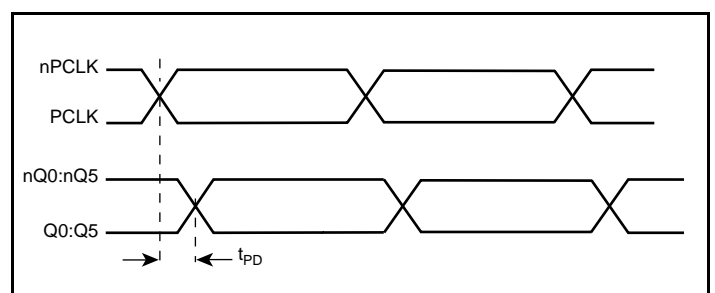
Differential Input Level



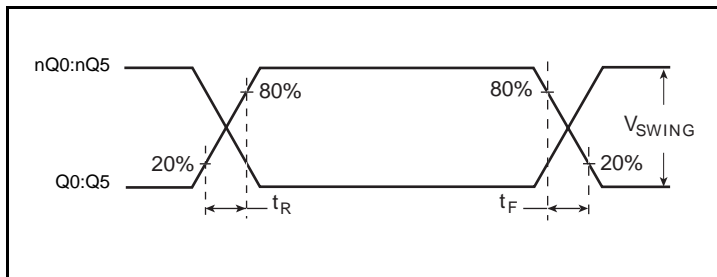
Part-to-Part Skew



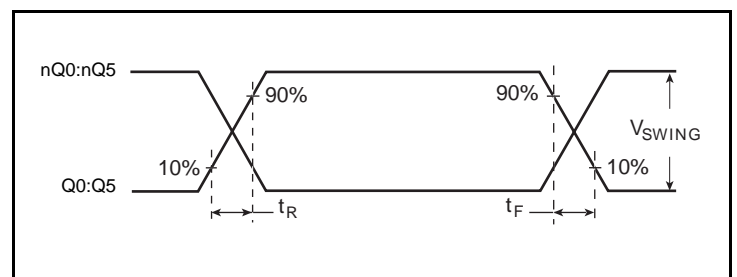
Output Skew



Propagation Delay



Output Rise/Fall Time



Output Rise/Fall Time

Application Information

Wiring the Differential Input to Accept Single-Ended Levels

Figure 1 shows how a differential input can be wired to accept single ended levels. The reference voltage $V_{REF} = V_{CC}/2$ is generated by the bias resistors R1 and R2. The bypass capacitor (C1) is used to help filter noise on the DC bias. This bias circuit should be located as close to the input pin as possible. The ratio of R1 and R2 might need to be adjusted to position the V_{REF} in the center of the input voltage swing. For example, if the input clock swing is 2.5V and $V_{CC} = 3.3V$, R1 and R2 value should be adjusted to set V_{REF} at 1.25V. The values below are for when both the single ended swing and V_{CC} are at the same voltage. This configuration requires that the sum of the output impedance of the driver (R_o) and the series resistance (R_s) equals the transmission line impedance. In addition, matched termination at the input will attenuate the signal in half. This can be done in one of two ways. First, R3 and R4 in parallel should equal the transmission

line impedance. For most 50Ω applications, R3 and R4 can be 100Ω. The values of the resistors can be increased to reduce the loading for slower and weaker LVCMOS driver. When using single-ended signaling, the noise rejection benefits of differential signaling are reduced. Even though the differential input can handle full rail LVCMOS signaling, it is recommended that the amplitude be reduced. The datasheet specifies a lower differential amplitude, however this only applies to differential signals. For single-ended applications, the swing can be larger, however V_{IL} cannot be less than $-0.3V$ and V_{IH} cannot be more than $V_{CC} + 0.3V$. Though some of the recommended components might not be used, the pads should be placed in the layout. They can be utilized for debugging purposes. The datasheet specifications are characterized and guaranteed by using a differential signal.

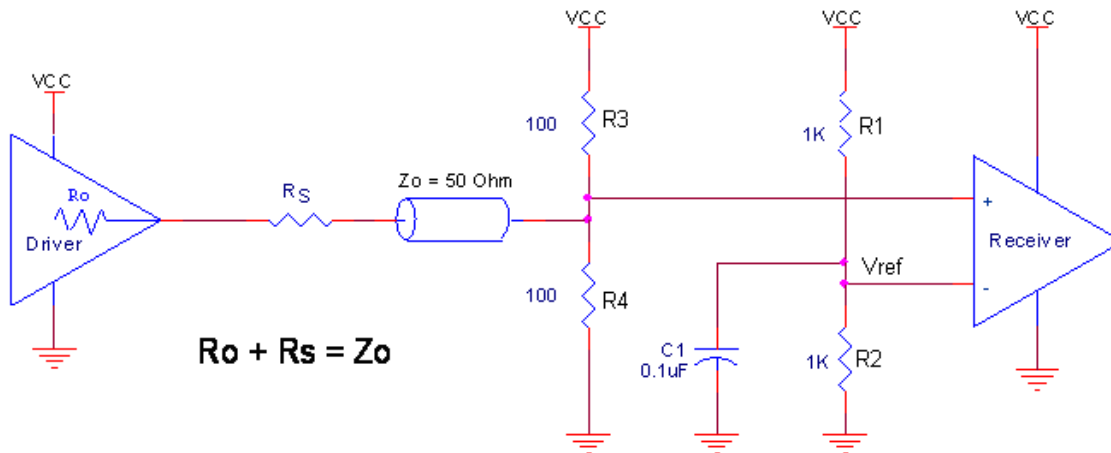


Figure 1. Recommended Schematic for Wiring a Differential Input to Accept Single-ended Levels

LVPECL Clock Input Interface

The PCLK /nPCLK accepts LVPECL, LVDS, CML and other differential signals. Both V_{SWING} and V_{OH} must meet the V_{PP} and V_{CMR} input requirements. Figures 3A to 3E show interface examples for the PCLK/nPCLK input driven by the most common driver types.

The input interfaces suggested here are examples only. If the driver is from another vendor, use their termination recommendation. Please consult with the vendor of the driver component to confirm the driver termination requirements.

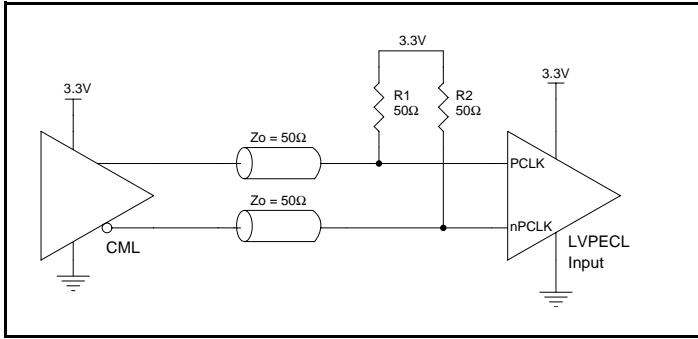


Figure 3A. PCLK/nPCLK Input Driven by a CML Driver

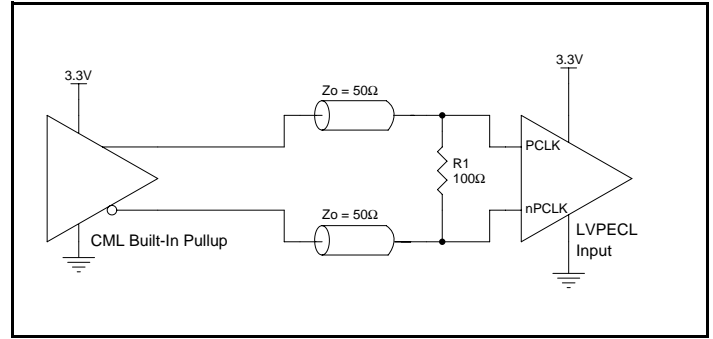


Figure 3B. PCLK/nPCLK Input Driven by a Built-In Pullup CML Driver

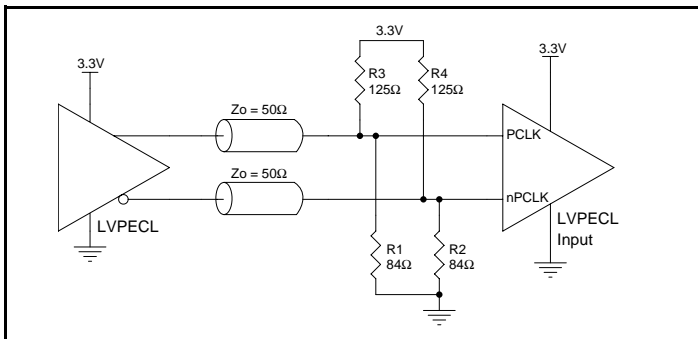


Figure 3C. PCLK/nPCLK Input Driven by a 3.3V LVPECL Driver

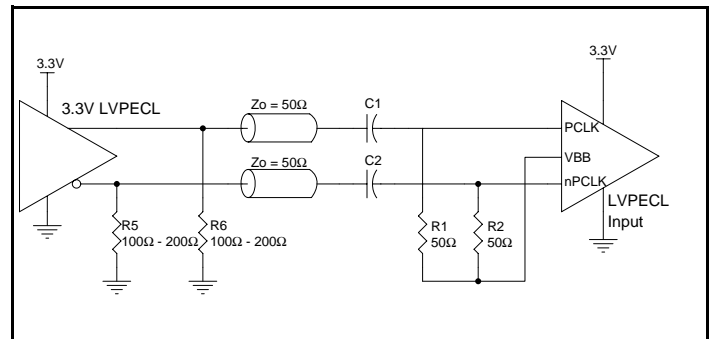


Figure 3D. PCLK/nPCLK Input Driven by a 3.3V LVPECL Driver with AC Couple

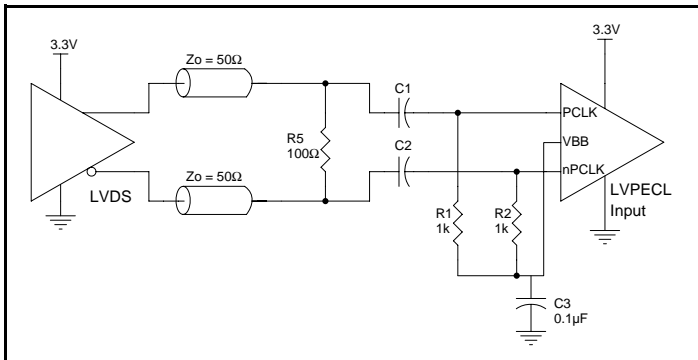


Figure 3E. PCLK/nPCLK Input Driven by a 3.3V LVDS Driver

Recommendations for Unused Output Pins

Outputs:

LVPECL Outputs

All unused LVPECL outputs can be left floating. We recommend that there is no trace attached. Both sides of the differential output pair should either be left floating or terminated.

Termination for 3.3V LVPECL Outputs

The clock layout topology shown below is a typical termination for LVPECL outputs. The two different layouts mentioned are recommended only as guidelines.

The differential outputs are low impedance follower outputs that generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are designed to drive 50Ω

transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion.

Figures 4A and 4B show two different layouts which are recommended only as guidelines. Other suitable clock layouts may exist and it would be recommended that the board designers simulate to guarantee compatibility across all printed circuit and clock component process variations.

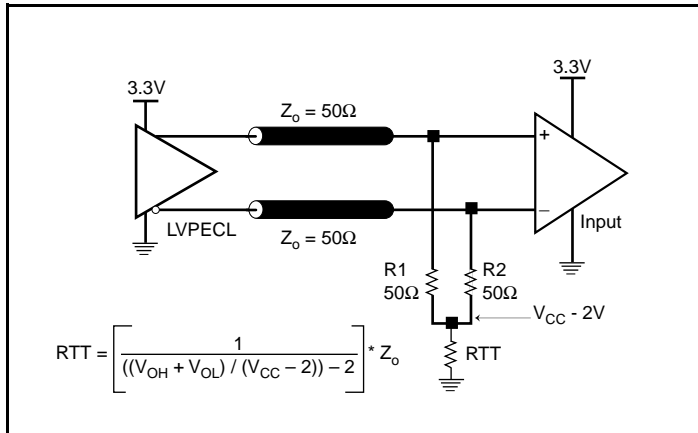


Figure 4A. 3.3V LVPECL Output Termination

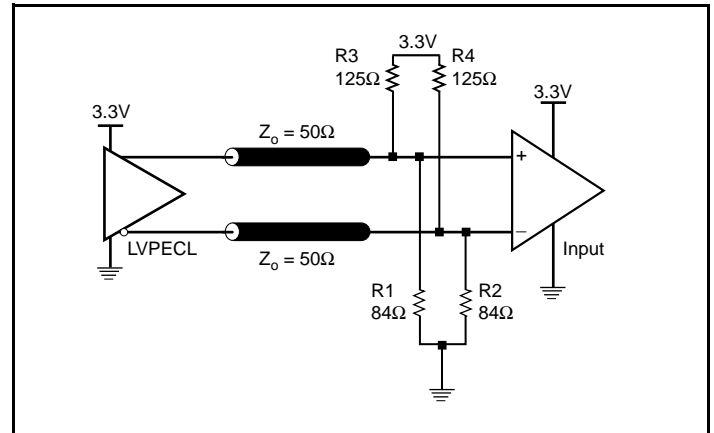


Figure 4B. 3.3V LVPECL Output Termination

Termination for 2.5V LVPECL Outputs

Figure 5A and Figure 5B show examples of termination for 2.5V LVPECL driver. These terminations are equivalent to terminating 50Ω to $V_{CC} - 2V$. For $V_{CC} = 2.5V$, the $V_{CC} - 2V$ is very close to ground

level. The R3 in Figure 5B can be eliminated and the termination is shown in Figure 5C.

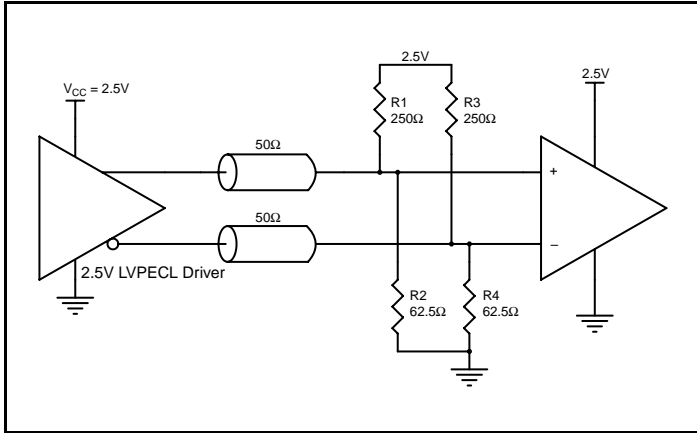


Figure 5A. 2.5V LVPECL Driver Termination Example

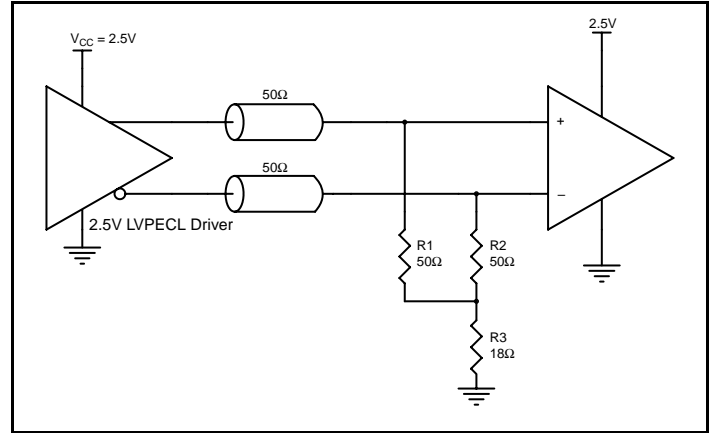


Figure 5B. 2.5V LVPECL Driver Termination Example

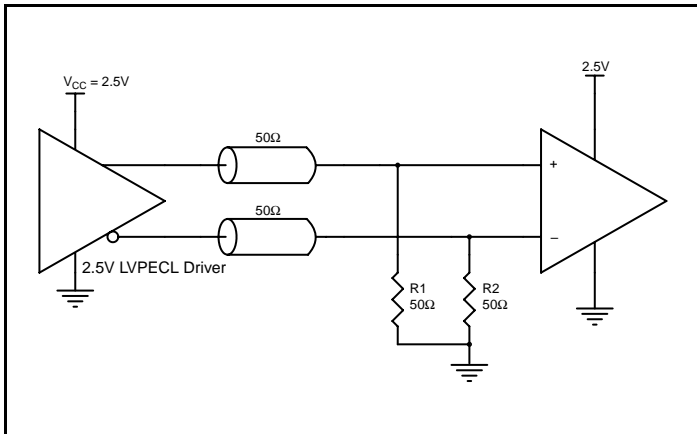


Figure 5C. 2.5V LVPECL Driver Termination Example

Schematic Example

Figure 6 shows a schematic example of ICS853S006I. The ICS853S006I input can accept various types of differential input signal. In this example, the inputs are driven by an LVPECL drivers. For the ICS853S006I LVPECL output driver, an example of LVPECL driver termination approach is shown in this schematic. Additional

LVPECL driver termination approaches are shown in the LVPECL Termination Application Note. It is recommended at least one decoupling capacitor per power pin. The decoupling capacitors should be physically located near the power pins. For ICS853S006I, the unused output can be left floating.

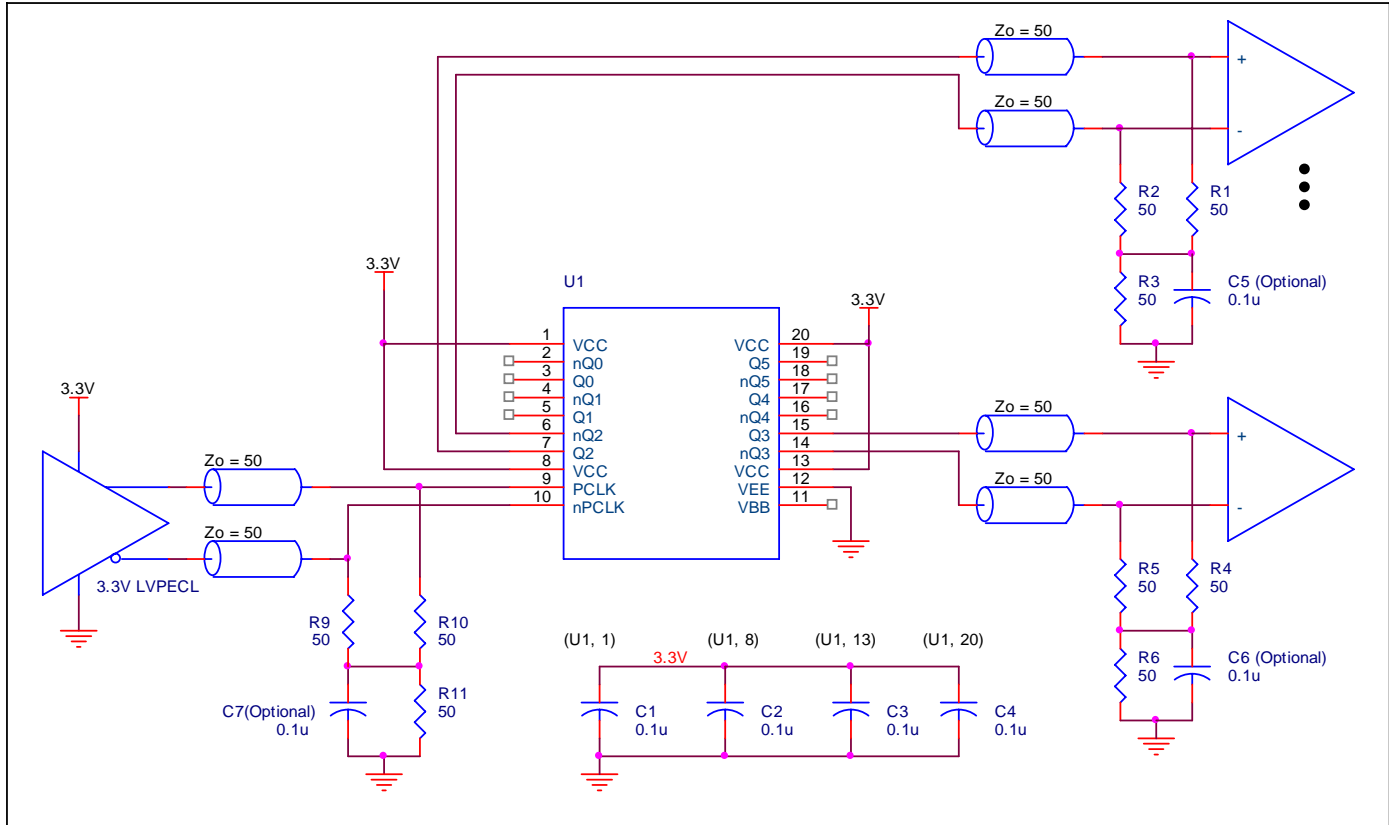


Figure 6. ICS853S006I Example LVPECL Clock Output Buffer Schematic

Power Considerations

This section provides information on power dissipation and junction temperature for the ICS853S006I. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS853S006I is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for $V_{CC} = 3.3V + 5\% = 3.465V$, which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)_{MAX} = $V_{CC_MAX} * I_{EE_MAX} = 3.465V * 60mA = \mathbf{207.9mW}$
- Power (outputs)_{MAX} = $\mathbf{32.02mW}$
If all outputs are loaded, the total power is $6 * 32.02mW = \mathbf{192.12mW}$

Total Power_{MAX} (3.465V, with all outputs switching) = $207.9mW + 192.12mW = \mathbf{400.02mW}$

2. Junction Temperature.

Junction temperature, T_j , is the temperature at the junction of the bond wire and bond pad directly affects the reliability of the device. The maximum recommended junction temperature for this device is 125°C. Limiting the internal transistor junction temperature, T_j , to 125°C ensures that the bond wire and bond pad temperature remains below 125°C.

The equation for T_j is as follows: $T_j = \theta_{JA} * Pd_total + T_A$

T_j = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is 92.1°C/W per Table 6 below.

Therefore, T_j for an ambient temperature of 85°C with all outputs switching is:

$$85^\circ\text{C} + 0.400\text{W} * 92.1^\circ\text{C/W} = 121.84^\circ\text{C}. \text{ This is below the limit of } 125^\circ\text{C}.$$

This calculation is only an example. T_j will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

Table 6. Thermal Resistance θ_{JA} for 20 Lead TSSOP, Forced Convection

θ_{JA} by Velocity			
Meters per Second	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	92.1°C/W	86.5°C/W	83.0°C/W

3. Calculations and Equations.

The purpose of this section is to calculate the power dissipation for the LVPECL output pairs.

LVPECL output driver circuit and termination are shown in *Figure 7*.

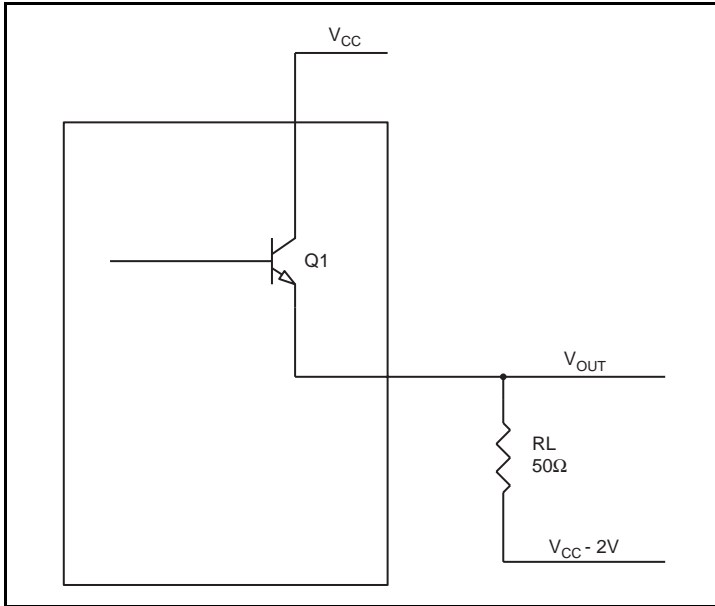


Figure 7. LVPECL Driver Circuit and Termination

To calculate worst case power dissipation into the load, use the following equations which assume a 50Ω load, and a termination voltage of $V_{CC} - 2V$.

- For logic high, $V_{OUT} = V_{OH_MAX} = V_{CC_MAX} - 0.88V$
 $(V_{CC_MAX} - V_{OH_MAX}) = 0.88V$
- For logic low, $V_{OUT} = V_{OL_MAX} = V_{CC_MAX} - 1.62V$
 $(V_{CC_MAX} - V_{OL_MAX}) = 1.62V$

Pd_H is power dissipation when the output drives high.

Pd_L is the power dissipation when the output drives low.

$$Pd_H = [(V_{OH_MAX} - (V_{CC_MAX} - 2V))/R_L] * (V_{CC_MAX} - V_{OH_MAX}) = [(2V - (V_{CC_MAX} - V_{OH_MAX}))/R_L] * (V_{CC_MAX} - V_{OH_MAX}) = [(2V - 0.88V)/50\Omega] * 0.88V = \mathbf{19.71mW}$$

$$Pd_L = [(V_{OL_MAX} - (V_{CC_MAX} - 2V))/R_L] * (V_{CC_MAX} - V_{OL_MAX}) = [(2V - (V_{CC_MAX} - V_{OL_MAX}))/R_L] * (V_{CC_MAX} - V_{OL_MAX}) = [(2V - 1.62V)/50\Omega] * 1.62V = \mathbf{12.31mW}$$

Total Power Dissipation per output pair = $Pd_H + Pd_L = \mathbf{32.02mW}$

Reliability Information

Table 7. θ_{JA} vs. Air Flow Table for a 20 Lead TSSOP

θ_{JA} by Velocity			
Meters per Second	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	92.1°C/W	86.5°C/W	83.0°C/W

Transistor Count

The transistor count for ICS853S006I is: 332

This device is pin and functional compatible with and is the suggested replacement for the ICS853006.

Package Outline and Package Dimensions

Package Outline - G Suffix for 20 Lead TSSOP

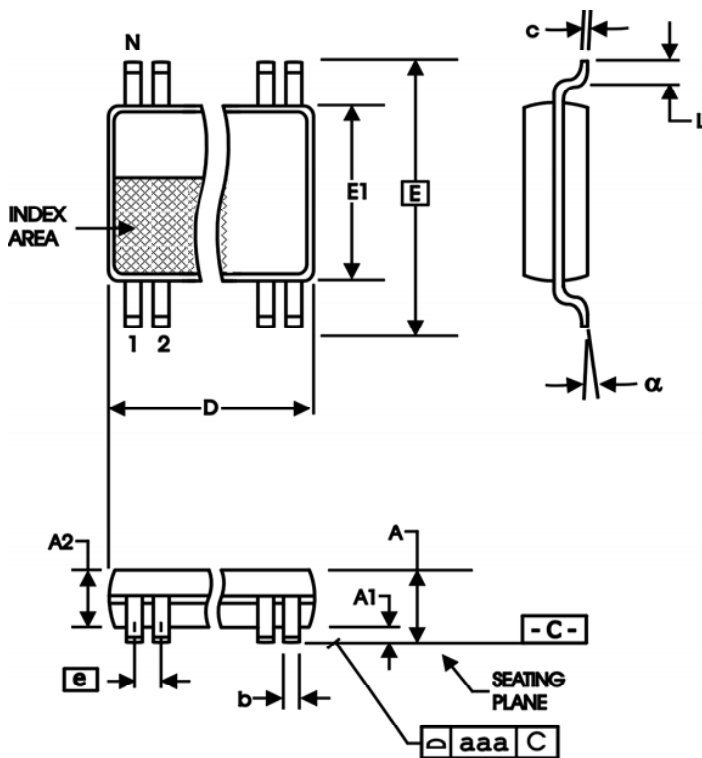


Table 8. Package Dimensions

All Dimensions in Millimeters		
Symbol	Minimum	Maximum
N	20	
A		1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	6.40	6.60
E	6.40 Basic	
E1	4.30	4.50
e	0.65 Basic	
L	0.45	0.75
α	0°	8°
aaa		0.10

Reference Document: JEDEC Publication 95, MO-153

Ordering Information

Table 9. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
853S006AGILF	ICS53S006AIL	20 Lead TSSOP	Tube	-40°C to 85°C
853S006AGILFT	ICS53S006AIL	20 Lead TSSOP	2500 Tape & Reel	-40°C to 85°C

NOTE: Parts that are ordered with an “LF” suffix to the part number are the Pb-Free configuration and are RoHS compliant.

Notice

1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation or any other use of the circuits, software, and information in the design of your product or system. Renesas Electronics disclaims any and all liability for any losses and damages incurred by you or third parties arising from the use of these circuits, software, or information.
2. Renesas Electronics hereby expressly disclaims any warranties against and liability for infringement or any other claims involving patents, copyrights, or other intellectual property rights of third parties, by or arising from the use of Renesas Electronics products or technical information described in this document, including but not limited to, the product data, drawings, charts, programs, algorithms, and application examples.
3. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
4. You shall not alter, modify, copy, or reverse engineer any Renesas Electronics product, whether in whole or in part. Renesas Electronics disclaims any and all liability for any losses or damages incurred by you or third parties arising from such alteration, modification, copying or reverse engineering.
5. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The intended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below.
 - "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; industrial robots; etc.
 - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control (traffic lights); large-scale communication equipment; key financial terminal systems; safety control equipment; etc.Unless expressly designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not intended or authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems; surgical implantations; etc.), or may cause serious property damage (space system; undersea repeaters; nuclear power control systems; aircraft control systems; key plant systems; military equipment; etc.). Renesas Electronics disclaims any and all liability for any damages or losses incurred by you or any third parties arising from the use of any Renesas Electronics product that is inconsistent with any Renesas Electronics data sheet, user's manual or other Renesas Electronics document.
6. When using Renesas Electronics products, refer to the latest product information (data sheets, user's manuals, application notes, "General Notes for Handling and Using Semiconductor Devices" in the reliability handbook, etc.), and ensure that usage conditions are within the ranges specified by Renesas Electronics with respect to maximum ratings, operating power supply voltage range, heat dissipation characteristics, installation, etc. Renesas Electronics disclaims any and all liability for any malfunctions, failure or accident arising out of the use of Renesas Electronics products outside of such specified ranges.
7. Although Renesas Electronics endeavors to improve the quality and reliability of Renesas Electronics products, semiconductor products have specific characteristics, such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Unless designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not subject to radiation resistance design. You are responsible for implementing safety measures to guard against the possibility of bodily injury, injury or damage caused by fire, and/or danger to the public in the event of a failure or malfunction of Renesas Electronics products, such as safety design for hardware and software, including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult and impractical, you are responsible for evaluating the safety of the final products or systems manufactured by you.
8. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. You are responsible for carefully and sufficiently investigating applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive, and using Renesas Electronics products in compliance with all these applicable laws and regulations. Renesas Electronics disclaims any and all liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
9. Renesas Electronics products and technologies shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You shall comply with any applicable export control laws and regulations promulgated and administered by the governments of any countries asserting jurisdiction over the parties or transactions.
10. It is the responsibility of the buyer or distributor of Renesas Electronics products, or any other party who distributes, disposes of, or otherwise sells or transfers the product to a third party, to notify such third party in advance of the contents and conditions set forth in this document.
11. This document shall not be reprinted, reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products.

(Note1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its directly or indirectly controlled subsidiaries.

(Note2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

(Rev.4.0-1 November 2017)

Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu,
Koto-ku, Tokyo 135-0061, Japan
www.renesas.com

Contact Information

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit:
www.renesas.com/contact/

Trademarks

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.